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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details

Product Status	Obsolete
Number of LABs/CLBs	80
Number of Logic Elements/Cells	640
Total RAM Bits	-
Number of I/O	159
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	256-LBGA
Supplier Device Package	256-FTBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lcmxo640e-5ft256c

June 2013

Data Sheet DS1002

Features

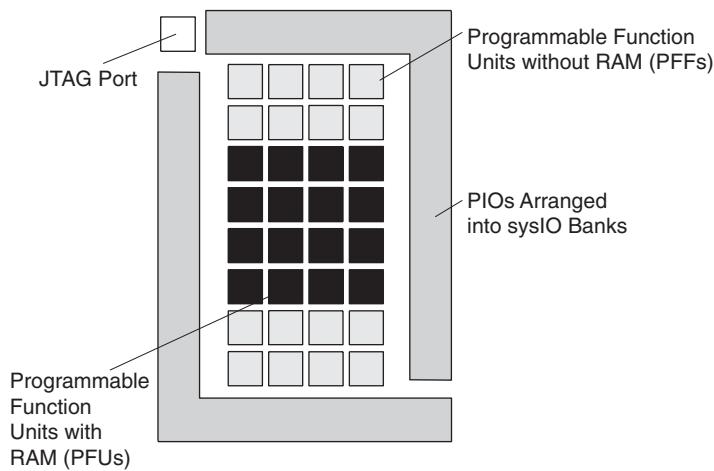
- **Non-volatile, Infinitely Reconfigurable**
 - Instant-on – powers up in microseconds
 - Single chip, no external configuration memory required
 - Excellent design security, no bit stream to intercept
 - Reconfigure SRAM based logic in milliseconds
 - SRAM and non-volatile memory programmable through JTAG port
 - Supports background programming of non-volatile memory
- **Sleep Mode**
 - Allows up to 100x static current reduction
- **TransFR™ Reconfiguration (TFR)**
 - In-field logic update while system operates
- **High I/O to Logic Density**
 - 256 to 2280 LUT4s
 - 73 to 271 I/Os with extensive package options
 - Density migration supported
 - Lead free/RoHS compliant packaging
- **Embedded and Distributed Memory**
 - Up to 27.6 Kbits sysMEM™ Embedded Block RAM
 - Up to 7.7 Kbits distributed RAM
 - Dedicated FIFO control logic

Table 1-1. MachXO Family Selection Guide

Device	LCMXO256	LCMXO640	LCMXO1200	LCMXO2280
LUTs	256	640	1200	2280
Dist. RAM (Kbits)	2.0	6.1	6.4	7.7
EBR SRAM (Kbits)	0	0	9.2	27.6
Number of EBR SRAM Blocks (9 Kbits)	0	0	1	3
V _{CC} Voltage	1.2/1.8/2.5/3.3V	1.2/1.8/2.5/3.3V	1.2/1.8/2.5/3.3V	1.2/1.8/2.5/3.3V
Number of PLLs	0	0	1	2
Max. I/O	78	159	211	271
Packages				
100-pin TQFP (14x14 mm)	78	74	73	73
144-pin TQFP (20x20 mm)		113	113	113
100-ball csBGA (8x8 mm)	78	74		
132-ball csBGA (8x8 mm)		101	101	101
256-ball caBGA (14x14 mm)		159	211	211
256-ball ftBGA (17x17 mm)		159	211	211
324-ball ftBGA (19x19 mm)				271

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Figure 2-3. Top View of the MachXO256 Device

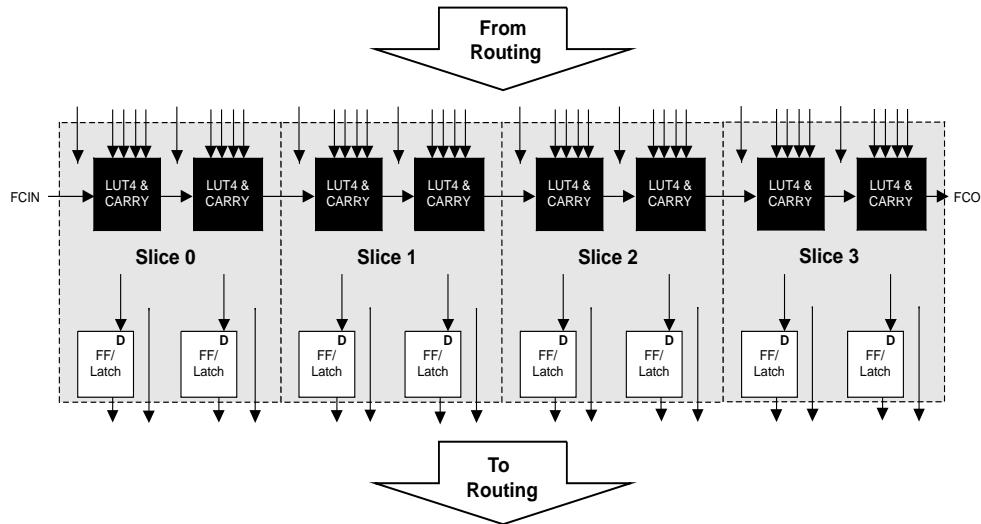


PFU Blocks

The core of the MachXO devices consists of PFU and PFF blocks. The PFUs can be programmed to perform Logic, Arithmetic, Distributed RAM, and Distributed ROM functions. PFF blocks can be programmed to perform Logic, Arithmetic, and Distributed ROM functions. Except where necessary, the remainder of this data sheet will use the term PFU to refer to both PFU and PFF blocks.

Each PFU block consists of four interconnected Slices, numbered 0-3 as shown in Figure 2-4. There are 53 inputs and 25 outputs associated with each PFU block.

Figure 2-4. PFU Diagram

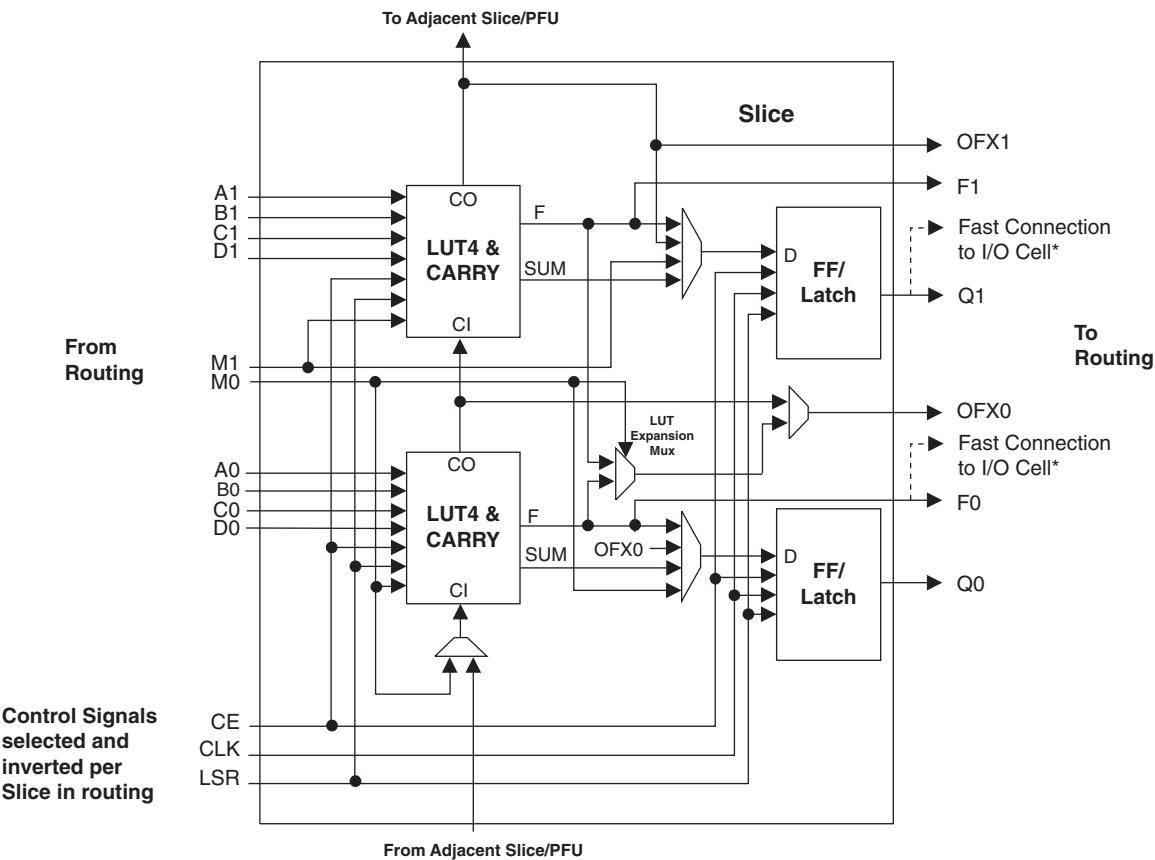


Slice

Each Slice contains two LUT4 lookup tables feeding two registers (programmed to be in FF or Latch mode), and some associated logic that allows the LUTs to be combined to perform functions such as LUT5, LUT6, LUT7, and LUT8. There is control logic to perform set/reset functions (programmable as synchronous/asynchronous), clock select, chip-select, and wider RAM/ROM functions. Figure 2-5 shows an overview of the internal logic of the Slice. The registers in the Slice can be configured for positive/negative and edge/level clocks.

There are 14 input signals: 13 signals from routing and one from the carry-chain (from the adjacent Slice/PFU). There are 7 outputs: 6 to the routing and one to the carry-chain (to the adjacent Slice/PFU). Table 2-1 lists the signals associated with each Slice.

Figure 2-5. Slice Diagram



Notes:

Some inter-Slice signals are not shown.

* Only PFUs at the edges have fast connections to the I/O cell.

Table 2-1. Slice Signal Descriptions

Function	Type	Signal Names	Description
Input	Data signal	A0, B0, C0, D0	Inputs to LUT4
Input	Data signal	A1, B1, C1, D1	Inputs to LUT4
Input	Multi-purpose	M0/M1	Multipurpose Input
Input	Control signal	CE	Clock Enable
Input	Control signal	LSR	Local Set/Reset
Input	Control signal	CLK	System Clock
Input	Inter-PFU signal	FCIN	Fast Carry In ¹
Output	Data signals	F0, F1	LUT4 output register bypass signals
Output	Data signals	Q0, Q1	Register Outputs
Output	Data signals	OFX0	Output of a LUT5 MUX
Output	Data signals	OFX1	Output of a LUT6, LUT7, LUT8 ² MUX depending on the Slice
Output	Inter-PFU signal	FCO	Fast Carry Out ¹

1. See Figure 2-4 for connection details.

2. Requires two PFUs.

The EBR memory supports three forms of write behavior for single or dual port operation:

1. **Normal** – data on the output appears only during the read cycle. During a write cycle, the data (at the current address) does not appear on the output. This mode is supported for all data widths.
2. **Write Through** – a copy of the input data appears at the output of the same port. This mode is supported for all data widths.
3. **Read-Before-Write** – when new data is being written, the old contents of the address appears at the output. This mode is supported for x9, x18 and x36 data widths.

FIFO Configuration

The FIFO has a write port with Data-in, CEW, WE and CLKW signals. There is a separate read port with Data-out, RCE, RE and CLKR signals. The FIFO internally generates Almost Full, Full, Almost Empty and Empty Flags. The Full and Almost Full flags are registered with CLKW. The Empty and Almost Empty flags are registered with CLKR. The range of programming values for these flags are in Table 2-7.

Table 2-7. Programmable FIFO Flag Ranges

Flag Name	Programming Range
Full (FF)	1 to (up to 2^N-1)
Almost Full (AF)	1 to Full-1
Almost Empty (AE)	1 to Full-1
Empty (EF)	0

N = Address bit width

The FIFO state machine supports two types of reset signals: RSTA and RSTB. The RSTA signal is a global reset that clears the contents of the FIFO by resetting the read/write pointer and puts the FIFO flags in their initial reset state. The RSTB signal is used to reset the read pointer. The purpose of this reset is to retransmit the data that is in the FIFO. In these applications it is important to keep careful track of when a packet is written into or read from the FIFO.

Memory Core Reset

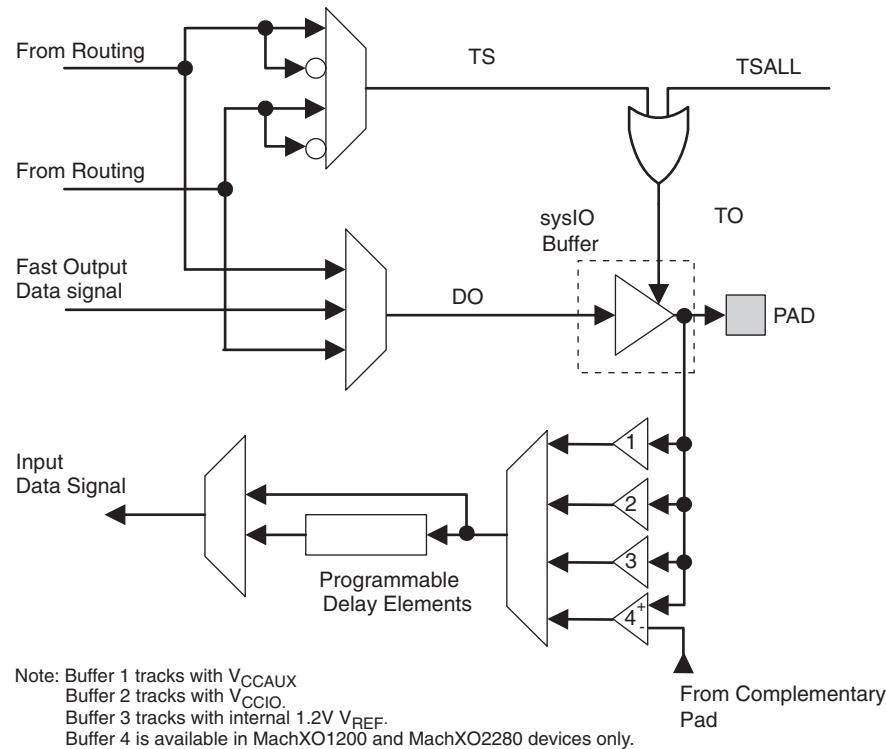
The memory array in the EBR utilizes latches at the A and B output ports. These latches can be reset asynchronously. RSTA and RSTB are local signals, which reset the output latches associated with Port A and Port B respectively. The Global Reset (GSRN) signal resets both ports. The output data latches and associated resets for both ports are as shown in Figure 2-13.

output data signals are multiplexed and provide a single signal to the I/O pin via the sysIO buffer. Figure 2-17 shows the MachXO PIO logic.

The tristate control signal is multiplexed from the output data signals and their complements. In addition a global signal (TSALL) from a dedicated pad can be used to tristate the sysIO buffer.

The PIO receives an input signal from the pin via the sysIO buffer and provides this signal to the core of the device. In addition there are programmable elements that can be utilized by the design tools to avoid positive hold times.

Figure 2-17. MachXO PIO Block Diagram



sysIO Buffer

Each I/O is associated with a flexible buffer referred to as a sysIO buffer. These buffers are arranged around the periphery of the device in groups referred to as Banks. The sysIO buffers allow users to implement the wide variety of standards that are found in today's systems including LVCMOS, TTL, BLVDS, LVDS and LVPECL.

In the MachXO devices, single-ended output buffers and ratioed input buffers (LVTTI, LVCMOS and PCI) are powered using V_{CCIO} . In addition to the Bank V_{CCIO} supplies, the MachXO devices have a V_{CC} core logic power supply, and a V_{CCAUX} supply that powers up a variety of internal circuits including all the differential and referenced input buffers.

MachXO256 and MachXO640 devices contain single-ended input buffers and single-ended output buffers with complementary outputs on all the I/O Banks.

MachXO1200 and MachXO2280 devices contain two types of sysIO buffer pairs.

1. Top and Bottom sysIO Buffer Pairs

The sysIO buffer pairs in the top and bottom Banks of the device consist of two single-ended output drivers and two sets of single-ended input buffers (for ratioed or absolute input levels). The I/O pairs on the top and bottom

Figure 2-20. MachXO640 Banks

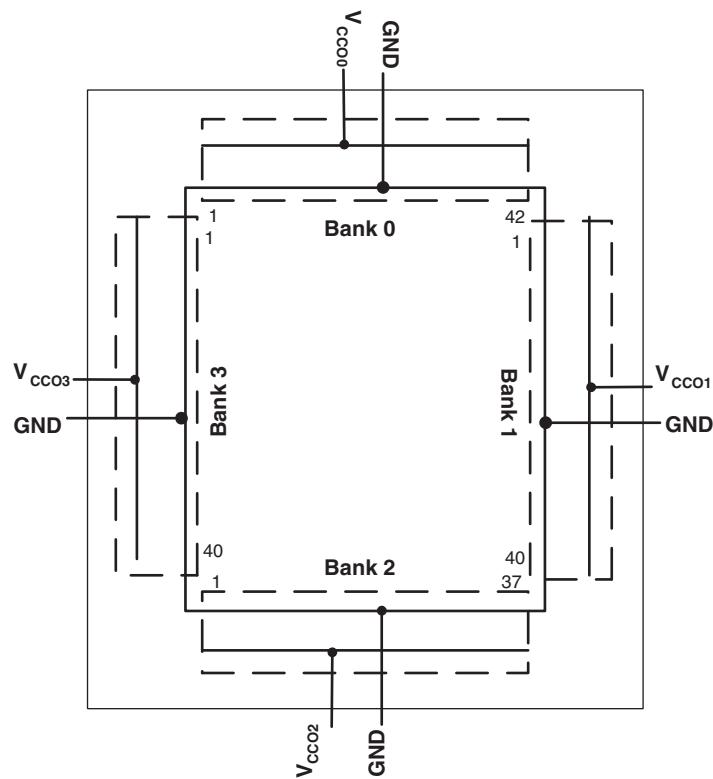
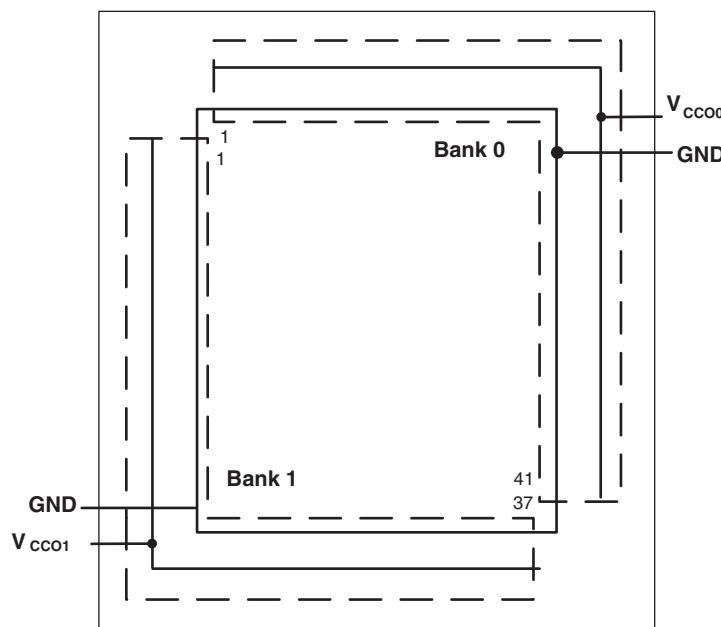


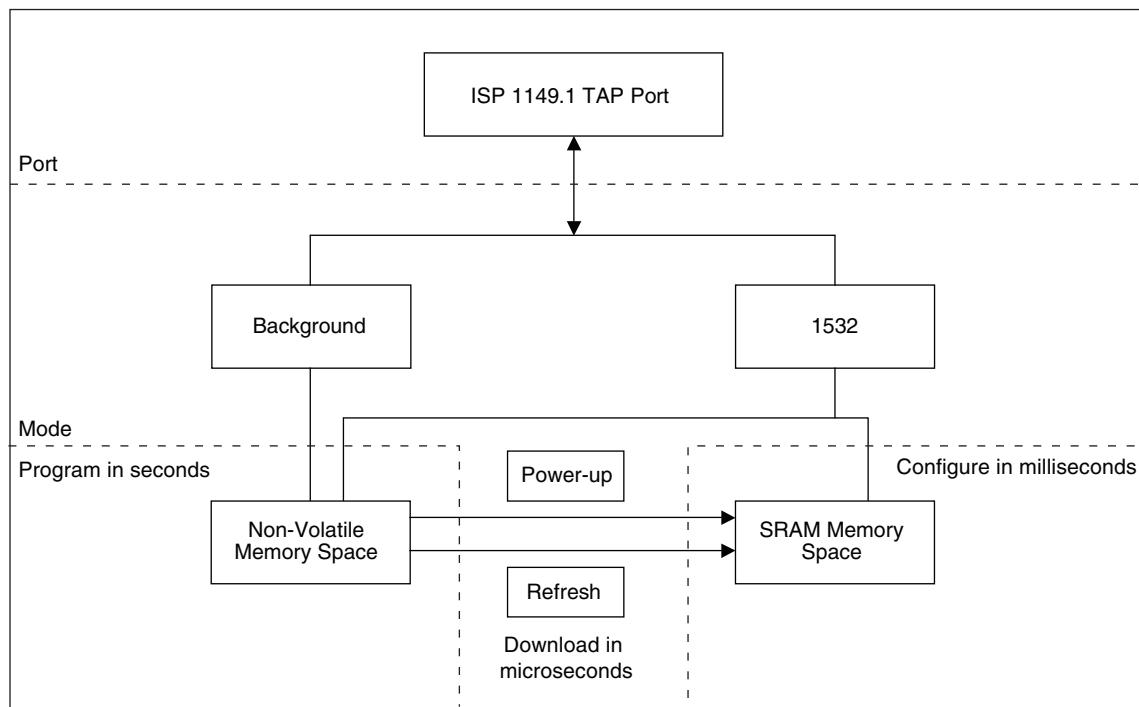
Figure 2-21. MachXO256 Banks



Hot Socketing

The MachXO devices have been carefully designed to ensure predictable behavior during power-up and power-down. Leakage into I/O pins is controlled to within specified limits. This allows for easy integration with the rest of

Figure 2-22. MachXO Configuration and Programming



Density Shifting

The MachXO family has been designed to enable density migration in the same package. Furthermore, the architecture ensures a high success rate when performing design migration from lower density parts to higher density parts. In many cases, it is also possible to shift a lower utilization design targeted for a high-density device to a lower density device. However, the exact details of the final resource utilization will impact the likely success in each case.



MachXO Family Data Sheet

DC and Switching Characteristics

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Absolute Maximum Ratings^{1, 2, 3}

	LCMXO E (1.2V)	LCMXO C (1.8V/2.5V/3.3V)
Supply Voltage V _{CC}	-0.5 to 1.32V	-0.5 to 3.75V
Supply Voltage V _{CCAUX}	-0.5 to 3.75V	-0.5 to 3.75V
Output Supply Voltage V _{CCIO}	-0.5 to 3.75V	-0.5 to 3.75V
I/O Tristate Voltage Applied ⁴	-0.5 to 3.75V	-0.5 to 3.75V
Dedicated Input Voltage Applied ⁴	-0.5 to 3.75V	-0.5 to 4.25V
Storage Temperature (ambient).....	-65 to 150°C	-65 to 150°C
Junction Temp. (T _j)	+125°C	+125°C

1. Stress above those listed under the "Absolute Maximum Ratings" may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.
2. Compliance with the Lattice *Thermal Management* document is required.
3. All voltages referenced to GND.
4. Overshoot and undershoot of -2V to (V_{IHMAX} + 2) volts is permitted for a duration of <20ns.

Recommended Operating Conditions¹

Symbol	Parameter	Min.	Max.	Units
V _{CC}	Core Supply Voltage for 1.2V Devices	1.14	1.26	V
	Core Supply Voltage for 1.8V/2.5V/3.3V Devices	1.71	3.465	V
V _{CCAUX} ³	Auxiliary Supply Voltage	3.135	3.465	V
V _{CCIO} ²	I/O Driver Supply Voltage	1.14	3.465	V
t _{TJCOM}	Junction Temperature Commercial Operation	0	+85	°C
t _{TJIND}	Junction Temperature Industrial Operation	-40	100	°C
t _{TFLASHCOM}	Junction Temperature, Flash Programming, Commercial	0	+85	°C
t _{TFLASHIND}	Junction Temperature, Flash Programming, Industrial	-40	100	°C

1. Like power supplies must be tied together. For example, if V_{CCIO} and V_{CC} are both 2.5V, they must also be the same supply. 3.3V V_{CCIO} and 1.2V V_{CCIO} should be tied to V_{CCAUX} or 1.2V V_{CC} respectively.
2. See recommended voltages by I/O standard in subsequent table.
3. V_{CC} must reach minimum V_{CC} value before V_{CCAUX} reaches 2.5V.

MachXO Programming/Erase Specifications

Symbol	Parameter	Min.	Max.	Units
N _{PROGCYC}	Flash Programming Cycles per t _{RETENTION}		1,000	Cycles
	Flash Functional Programming Cycles		10,000	Cycles
t _{RETENTION}	Data Retention at 125° Junction Temperature	10		Years

sysIO Differential Electrical Characteristics

LVDS

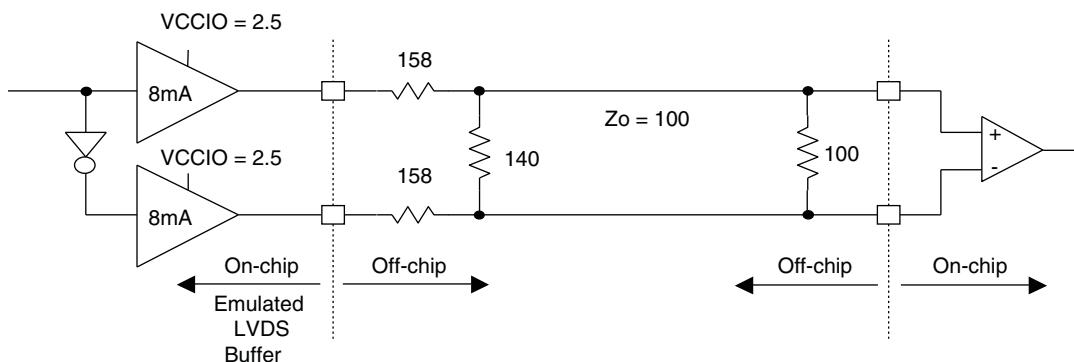
Over Recommended Operating Conditions

Parameter Symbol	Parameter Description	Test Conditions	Min.	Typ.	Max.	Units
V_{INP}, V_{INM}	Input Voltage		0	—	2.4	V
V_{THD}	Differential Input Threshold		+/-100	—	—	mV
V_{CM}	Input Common Mode Voltage	$100\text{mV} \leq V_{THD}$	$V_{THD}/2$	1.2	1.8	V
		$200\text{mV} \leq V_{THD}$	$V_{THD}/2$	1.2	1.9	V
		$350\text{mV} \leq V_{THD}$	$V_{THD}/2$	1.2	2.0	V
I_{IN}	Input current	Power on	—	—	+/-10	μA
V_{OH}	Output high voltage for V_{OP} or V_{OM}	$R_T = 100 \text{ Ohm}$	—	1.38	1.60	V
V_{OL}	Output low voltage for V_{OP} or V_{OM}	$R_T = 100 \text{ Ohm}$	0.9V	1.03	—	V
V_{OD}	Output voltage differential	$(V_{OP} - V_{OM}), R_T = 100 \text{ Ohm}$	250	350	450	mV
ΔV_{OD}	Change in V_{OD} between high and low		—	—	50	mV
V_{OS}	Output voltage offset	$(V_{OP} - V_{OM})/2, R_T = 100 \text{ Ohm}$	1.125	1.25	1.375	V
ΔV_{OS}	Change in V_{OS} between H and L		—	—	50	mV
I_{OSD}	Output short circuit current	$V_{OD} = 0\text{V}$ Driver outputs shorted	—	—	6	mA

LVDS Emulation

MachXO devices can support LVDS outputs via emulation (LVDS25E), in addition to the LVDS support that is available on-chip on certain devices. The output is emulated using complementary LVCMS outputs in conjunction with resistors across the driver outputs on all devices. The scheme shown in Figure 3-1 is one possible solution for LVDS standard implementation. Resistor values in Figure 3-1 are industry standard values for 1% resistors.

Figure 3-1. LVDS Using External Resistors (LVDS25E)



Note: All resistors are $\pm 1\%$.

The LVDS differential input buffers are available on certain devices in the MachXO family.

MachXO Family Timing Adders^{1, 2, 3}

Over Recommended Operating Conditions

Buffer Type	Description	-5	-4	-3	Units
Input Adjusters					
LVDS25 ⁴	LVDS	0.44	0.53	0.61	ns
BLVDS25 ⁴	BLVDS	0.44	0.53	0.61	ns
LVPECL33 ⁴	LVPECL	0.42	0.50	0.59	ns
LVTTL33	LVTTL	0.01	0.01	0.01	ns
LVCMOS33	LVCMOS 3.3	0.01	0.01	0.01	ns
LVCMOS25	LVCMOS 2.5	0.00	0.00	0.00	ns
LVCMOS18	LVCMOS 1.8	0.07	0.08	0.10	ns
LVCMOS15	LVCMOS 1.5	0.14	0.17	0.19	ns
LVCMOS12	LVCMOS 1.2	0.40	0.48	0.56	ns
PCI33 ⁴	PCI	0.01	0.01	0.01	ns
Output Adjusters					
LVDS25E	LVDS 2.5 E	-0.13	-0.15	-0.18	ns
LVDS25 ⁴	LVDS 2.5	-0.21	-0.26	-0.30	ns
BLVDS25	BLVDS 2.5	-0.03	-0.03	-0.04	ns
LVPECL33	LVPECL 3.3	0.04	0.04	0.05	ns
LVTTL33_4mA	LVTTL 4mA drive	0.04	0.04	0.05	ns
LVTTL33_8mA	LVTTL 8mA drive	0.06	0.07	0.08	ns
LVTTL33_12mA	LVTTL 12mA drive	-0.01	-0.01	-0.01	ns
LVTTL33_16mA	LVTTL 16mA drive	0.50	0.60	0.70	ns
LVCMOS33_4mA	LVCMOS 3.3 4mA drive	0.04	0.04	0.05	ns
LVCMOS33_8mA	LVCMOS 3.3 8mA drive	0.06	0.07	0.08	ns
LVCMOS33_12mA	LVCMOS 3.3 12mA drive	-0.01	-0.01	-0.01	ns
LVCMOS33_14mA	LVCMOS 3.3 14mA drive	0.50	0.60	0.70	ns
LVCMOS25_4mA	LVCMOS 2.5 4mA drive	0.05	0.06	0.07	ns
LVCMOS25_8mA	LVCMOS 2.5 8mA drive	0.10	0.12	0.13	ns
LVCMOS25_12mA	LVCMOS 2.5 12mA drive	0.00	0.00	0.00	ns
LVCMOS25_14mA	LVCMOS 2.5 14mA drive	0.34	0.40	0.47	ns
LVCMOS18_4mA	LVCMOS 1.8 4mA drive	0.11	0.13	0.15	ns
LVCMOS18_8mA	LVCMOS 1.8 8mA drive	0.05	0.06	0.06	ns
LVCMOS18_12mA	LVCMOS 1.8 12mA drive	-0.06	-0.07	-0.08	ns
LVCMOS18_14mA	LVCMOS 1.8 14mA drive	0.06	0.07	0.09	ns
LVCMOS15_4mA	LVCMOS 1.5 4mA drive	0.15	0.19	0.22	ns
LVCMOS15_8mA	LVCMOS 1.5 8mA drive	0.05	0.06	0.07	ns
LVCMOS12_2mA	LVCMOS 1.2 2mA drive	0.26	0.31	0.36	ns
LVCMOS12_6mA	LVCMOS 1.2 6mA drive	0.05	0.06	0.07	ns
PCI33 ⁴	PCI33	1.85	2.22	2.59	ns

1. Timing adders are characterized but not tested on every device.
2. LVCMOS timing is measured with the load specified in Switching Test Conditions table.
3. All other standards tested according to the appropriate specifications.
4. I/O standard only available in LCMXO1200 and LCMXO2280 devices.

Rev. A 0.19

Power Supply and NC (Cont.)

Signal	132 csBGA ¹	256 caBGA / 256 ftBGA ¹	324 ftBGA ¹
VCC	H3, P6, G12, C7	G7, G10, K7, K10	F14, G11, G9, H7, L7, M9
VCCIO0	LCMxo640: B11, C5 LCMxo1200/2280: C5	LCMxo640: F8, F7, F9, F10 LCMxo1200/2280: F8, F7	G8, G7
VCCIO1	LCMxo640: L12, E12 LCMxo1200/2280: B11	LCMxo640: H11, G11, K11, J11 LCMxo1200/2280: F9, F10	G12, G10
VCCIO2	LCMxo640: N2, M10 LCMxo1200/2280: E12	LCMxo640: L9, L10, L8, L7 LCMxo1200/2280: H11, G11	J12, H12
VCCIO3	LCMxo640: D2, K3 LCMxo1200/2280: L12	LCMxo640: K6, J6, H6, G6 LCMxo1200/2280: K11, J11	L12, K12
VCCIO4	LCMxo640: None LCMxo1200/2280: M10	LCMxo640: None LCMxo1200/2280: L9, L10	M12, M11
VCCIO5	LCMxo640: None LCMxo1200/2280: N2	LCMxo640: None LCMxo1200/2280: L8, L7	M8, R9
VCCIO6	LCMxo640: None LCMxo1200/2280: K3	LCMxo640: None LCMxo1200/2280: K6, J6	M7, K7
VCCIO7	LCMxo640: None LCMxo1200/2280: D2	LCMxo640: None LCMxo1200/2280: H6, G6	H6, J7
VCCAUX	P7, A7	T9, A8	M10, F9
GND ²	F1, P9, J14, C9, A10, B4, L13, D13, P2, N11, E1, L2	A1, A16, F11, G8, G9, H7, H8, H9, H10, J7, J8, J9, J10, K8, K9, L6, T1, T16	E14, F16, H10, H11, H8, H9, J10, J11, J4, J8, J9, K10, K11, K17, K8, K9, L10, L11, L8, L9, N2, P14, P5, R7
NC ³	—	LCMxo640: E4, E5, F5, F6, C3, C2, G4, G5, H4, H5, K5, K4, M5, M4, P2, P3, N5, N6, M7, M8, N10, N11, R15, R16, P15, P16, M11, L11, N12, N13, M13, M12, K12, J12, F12, F13, E12, E13, D13, D14, B15, A15, C14, B14, E11, E10, E7, E6, D4, D3, B3, B2 LCMxo1200: None LCMxo2280: None	—

1. Pin orientation A1 starts from the upper left corner of the top side view with alphabetical order ascending vertically and numerical order ascending horizontally.
2. All grounds must be electrically connected at the board level. For fpBGA and ftBGA packages, the total number of GND balls is less than the actual number of GND logic connections from the die to the common package GND plane.
3. NC pins should not be connected to any active signals, VCC or GND.

LCMxo256 and LCMxo640 Logic Signal Connections: 100 csBGA

LCMxo256					LCMxo640				
Ball Number	Ball Function	Bank	Dual Function	Differential	Ball Number	Ball Function	Bank	Dual Function	Differential
B1	PL2A	1		T	B1	PL2A	3		T
C1	PL2B	1		C	C1	PL2C	3		T
D2	PL3A	1		T	D2	PL2B	3		C
D1	PL3B	1		C	D1	PL2D	3		C
C2	PL3C	1		T	C2	PL3A	3		T
E1	PL3D	1		C	E1	PL3B	3		C
E2	PL4A	1		T	E2	PL3C	3		T
F1	PL4B	1		C	F1	PL3D	3		C
F2	PL5A	1		T	F2	PL4A	3		
G2	PL5B	1		C	G2	PL4C	3		T
H1	GNDIO1	1			H1	GNDIO3	3		
H2	PL5C	1		T	H2	PL4D	3		C
J1	PL5D	1	GSRN	C	J1	PL5B	3	GSRN	
J2	PL6A	1		T	J2	PL7B	3		
K1	PL6B	1	TSALL	C	K1	PL8C	3	TSALL	T
K2	PL7A	1		T	K2	PL8D	3		C
L1	PL7B	1		C	L1	PL9A	3		
L2	PL7C	1		T	L2	PL9C	3		
M1	PL7D	1		C	M1	PL10A	3		
M2	PL8A	1		T	M2	PL10C	3		
N1	PL8B	1		C	N1	PL11A	3		
M3	PL9A	1		T	M3	PL11C	3		
N2	GNDIO1	1			N2	GNDIO3	3		
P2	TMS	1	TMS		P2	TMS	2	TMS	
P3	PL9B	1		C	P3	PB2C	2		
N4	TCK	1	TCK		N4	TCK	2	TCK	
P4	PB2A	1		T	P4	VCCIO2	2		
N3	PB2B	1		C	N3	GNDIO2	2		
P5	TDO	1	TDO		P5	TDO	2	TDO	
N5	PB2C	1		T	N5	PB4C	2		
P6	TDI	1	TDI		P6	TDI	2	TDI	
N6	PB2D	1		C	N6	PB4E	2		
P7	VCC	-			P7	VCC	-		
N7	PB3A	1	PCLK1_1**	T	N7	PB5B	2	PCLK2_1**	
P8	PB3B	1		C	P8	PB5D	2		
N8	PB3C	1	PCLK1_0**	T	N8	PB6B	2	PCLK2_0**	
P9	PB3D	1		C	P9	PB6C	2		
N10	GNDIO1	1			N10	GNDIO2	2		
P11	PB4A	1		T	P11	PB8B	2		
N11	PB4B	1		C	N11	PB8C	2		T
P12	PB4C	1		T	P12	PB8D	2		C
N12	PB4D	1		C	N12	PB9A	2		

**LCMXX640, LCMXO1200 and LCMXO2280 Logic Signal Connections:
144 TQFP**

Pin Number	LCMXX640				LCMXX1200				LCMXX2280				
	Ball Function	Bank	Dual Function	Differential	Ball Function	Bank	Dual Function	Differential	Ball Function	Bank	Dual Function	Differential	
1	PL2A	3		T	PL2A	7			T	PL2A	7	LUM0_PLLT_FB_A	T
2	PL2C	3		T	PL2B	7			C	PL2B	7	LUM0_PLLC_FB_A	C
3	PL2B	3		C	PL3A	7			T*	PL3A	7		T*
4	PL3A	3		T	PL3B	7			C*	PL3B	7		C*
5	PL2D	3		C	PL3C	7			T	PL3C	7	LUM0_PLLT_IN_A	T
6	PL3B	3		C	PL3D	7			C	PL3D	7	LUM0_PLLC_IN_A	C
7	PL3C	3		T	PL4A	7			T*	PL4A	7		T*
8	PL3D	3		C	PL4B	7			C*	PL4B	7		C*
9	PL4A	3			PL4C	7				PL4C	7		
10	VCCIO3	3			VCCIO7	7				VCCIO7	7		
11	GNDIO3	3			GNDIO7	7				GNDIO7	7		
12	PL4D	3			PL5C	7				PL6C	7		
13	PL5A	3		T	PL6A	7			T*	PL7A	7		T*
14	PL5B	3	GSRN	C	PL6B	7	GSRN		C*	PL7B	7	GSRN	C*
15	PL5D	3			PL6D	7				PL7D	7		
16	GND	-			GND	-				GND	-		
17	PL6C	3		T	PL7C	7			T	PL9C	7		T
18	PL6D	3		C	PL7D	7			C	PL9D	7		C
19	PL7A	3		T	PL10A	6			T*	PL13A	6		T*
20	PL7B	3		C	PL10B	6			C*	PL13B	6		C*
21	VCC	-			VCC	-				VCC	-		
22	PL8A	3		T	PL11A	6			T*	PL13D	6		
23	PL8B	3		C	PL11B	6			C*	PL14D	6		C
24	PL8C	3	TSALL		PL11C	6	TSALL			PL14C	6	TSALL	T
25	PL9C	3		T	PL12B	6				PL15B	6		
26	VCCIO3	3			VCCIO6	6				VCCIO6	6		
27	GNDIO3	3			GNDIO6	6				GNDIO6	6		
28	PL9D	3		C	PL13D	6				PL16D	6		
29	PL10A	3		T	PL14A	6	LLM0_PLLT_FB_A	T*		PL17A	6	LLM0_PLLT_FB_A	T*
30	PL10B	3		C	PL14B	6	LLM0_PLLC_FB_A	C*		PL17B	6	LLM0_PLLC_FB_A	C*
31	PL10C	3		T	PL14C	6			T	PL17C	6		T
32	PL11A	3		T	PL14D	6			C	PL17D	6		C
33	PL10D	3		C	PL15A	6	LLM0_PLLT_IN_A	T*		PL18A	6	LLM0_PLLT_IN_A	T*
34	PL11C	3		T	PL15B	6	LLM0_PLLC_IN_A	C*		PL18B	6	LLM0_PLLC_IN_A	C*
35	PL11B	3		C	PL16A	6			T	PL19A	6		T
36	PL11D	3		C	PL16B	6			C	PL19B	6		C
37	GNDIO2	2			GNDIO5	5				GNDIO5	5		
38	VCCIO2	2			VCCIO5	5				VCCIO5	5		
39	TMS	2	TMS		TMS	5	TMS			TMS	5	TMS	
40	PB2C	2			PB2C	5			T	PB2A	5		T
41	PB3A	2		T	PB2D	5			C	PB2B	5		C
42	TCK	2	TCK		TCK	5	TCK			TCK	5	TCK	
43	PB3B	2		C	PB3A	5			T	PB3A	5		T
44	PB3C	2		T	PB3B	5			C	PB3B	5		C
45	PB3D	2		C	PB4A	5			T	PB4A	5		T
46	PB4A	2		T	PB4B	5			C	PB4B	5		C
47	TDO	2	TDO		TDO	5	TDO			TDO	5	TDO	
48	PB4B	2		C	PB4D	5				PB4D	5		
49	PB4C	2		T	PB5A	5			T	PB5A	5		T
50	PB4D	2		C	PB5B	5			C	PB5B	5		C

**LCMxo640, LCMxo1200 and LCMxo2280 Logic Signal Connections:
 144 TQFP (Cont.)**

Pin Number	LCMxo640				LCMxo1200				LCMxo2280				
	Ball Function	Bank	Dual Function	Differential	Ball Function	Bank	Dual Function	Differential	Ball Function	Bank	Dual Function	Differential	
101	PR3D	1		C	PR4B	2			C*	PR5B	2		C*
102	PR3C	1		T	PR4A	2			T*	PR5A	2		T*
103	PR3B	1		C	PR3D	2			C	PR4D	2		C
104	PR2D	1		C	PR3C	2			T	PR4C	2		T
105	PR3A	1		T	PR3B	2			C*	PR4B	2		C*
106	PR2B	1		C	PR3A	2			T*	PR4A	2		T*
107	PR2C	1		T	PR2B	2			C	PR3B	2		C*
108	PR2A	1		T	PR2A	2			T	PR3A	2		T*
109	PT9F	0		C	PT11D	1			C	PT16D	1		C
110	PT9D	0		C	PT11C	1			T	PT16C	1		T
111	PT9E	0		T	PT11B	1			C	PT16B	1		C
112	PT9B	0		C	PT11A	1			T	PT16A	1		T
113	PT9C	0		T	PT10F	1			C	PT15D	1		C
114	PT9A	0		T	PT10E	1			T	PT15C	1		T
115	PT8C	0			PT10D	1			C	PT14B	1		C
116	PT8B	0		C	PT10C	1			T	PT14A	1		T
117	VCCIO0	0			VCCIO1	1				VCCIO1	1		
118	GNDIO0	0			GNDIO1	1				GNDIO1	1		
119	PT8A	0		T	PT9F	1			C	PT12F	1		C
120	PT7E	0			PT9E	1			T	PT12E	1		T
121	PT7C	0			PT9B	1			C	PT12D	1		C
122	PT7A	0			PT9A	1			T	PT12C	1		T
123	GND	-			GND	-				GND	-		
124	PT6B	0	PCLK0_1***	C	PT7D	1	PCLK1_1***			PT10B	1	PCLK1_1***	
125	PT6A	0		T	PT7B	1			C	PT9D	1		C
126	PT5C	0			PT7A	1			T	PT9C	1		T
127	PT5B	0	PCLK0_0***		PT6F	0	PCLK1_0***			PT9B	1	PCLK1_0***	
128	VCCAUX	-			VCCAUX	-				VCCAUX	-		
129	VCC	-			VCC	-				VCC	-		
130	PT4D	0			PT5D	0			C	PT7B	0		C
131	PT4B	0		C	PT5C	0			T	PT7A	0		T
132	PT4A	0		T	PT5B	0			C	PT6D	0		
133	PT3F	0			PT5A	0			T	PT6E	0		T
134	PT3D	0			PT4B	0				PT6F	0		C
135	VCCIO0	0			VCCIO0	0				VCCIO0	0		
136	GNDIO0	0			GNDIO0	0				GNDIO0	0		
137	PT3B	0		C	PT3D	0			C	PT4B	0		T
138	PT2F	0		C	PT3C	0			T	PT4A	0		C
139	PT3A	0		T	PT3B	0			C	PT3B	0		C
140	PT2D	0		C	PT3A	0			T	PT3A	0		T
141	PT2E	0		T	PT2D	0			C	PT2D	0		C
142	PT2B	0		C	PT2C	0			T	PT2C	0		T
143	PT2C	0		T	PT2B	0			C	PT2B	0		C
144	PT2A	0		T	PT2A	0			T	PT2A	0		T

*Supports true LVDS outputs.

**NC for "E" devices.

***Primary clock inputs are single-ended.

LCMxo2280 Logic Signal Connections: 324 ftBGA (Cont.)

LCMxo2280				
Ball Number	Ball Function	Bank	Dual Function	Differential
G2	PL11A	6		T*
H2	PL11B	6		C*
L3	PL11C	6		T
L5	PL11D	6		C
H1	PL12A	6		T*
VCCIO6	VCCIO6	6		
GND	GNDIO6	6		
J2	PL12B	6		C*
L4	PL12C	6		T
L6	PL12D	6		C
K2	PL13A	6		T*
K1	PL13B	6		C*
J1	PL13C	6		T
VCC	VCC	-		
L2	PL13D	6		C
M5	PL14D	6		C
M3	PL14C	6	TSALL	T
L1	PL14B	6		C*
M2	PL14A	6		T*
M1	PL15A	6		T*
N1	PL15B	6		C*
M6	PL15C	6		T
M4	PL15D	6		C
VCCIO6	VCCIO6	6		
GND	GNDIO6	6		
P1	PL16A	6		T*
P2	PL16B	6		C*
N3	PL16C	6		T
N4	PL16D	6		C
GND	GND	-		
T1	PL17A	6	LLM0_PLLT_FB_A	T*
R1	PL17B	6	LLM0_PLLC_FB_A	C*
P3	PL17C	6		T
N5	PL17D	6		C
R3	PL18A	6	LLM0_PLLT_IN_A	T*
R2	PL18B	6	LLM0_PLLC_IN_A	C*
P4	PL19A	6		T
N6	PL19B	6		C
U1	PL20A	6		T
VCCIO6	VCCIO6	6		
GND	GNDIO6	6		
GND	GNDIO5	5		
VCCIO5	VCCIO5	5		

LCMxo2280 Logic Signal Connections: 324 ftBGA (Cont.)

LCMxo2280				
Ball Number	Ball Function	Bank	Dual Function	Differential
V10	PB9B	4		C
N10	PB9C	4		T
R10	PB9D	4		C
P10	PB10F	4	PCLK4_1***	C
T10	PB10E	4		T
U10	PB10D	4		C
V11	PB10C	4		T
U11	PB10B	4	PCLK4_0***	C
VCCIO4	VCCIO4	4		
GND	GNDIO4	4		
T11	PB10A	4		T
U12	PB11A	4		T
R11	PB11B	4		C
GND	GND	-		
T12	PB11C	4		T
P11	PB11D	4		C
V12	PB12A	4		T
V13	PB12B	4		C
R12	PB12C	4		T
N11	PB12D	4		C
U13	PB12E	4		T
VCCIO4	VCCIO4	4		
GND	GNDIO4	4		
V14	PB12F	4		C
T13	PB13A	4		T
P12	PB13B	4		C
R13	PB13C	4		T
N12	PB13D	4		C
V15	PB14A	4		T
U14	PB14B	4		C
V16	PB14C	4		T
GND	GND	-		
T14	PB14D	4		C
U15	PB15A	4		T
V17	PB15B	4		C
P13**	SLEEPN	-	SLEEPN	
T15	PB15D	4		
U16	PB16A	4		T
V18	PB16B	4		C
N13	PB16C	4		T
R14	PB16D	4		C
VCCIO4	VCCIO4	4		
GND	GNDIO4	4		

LCMxo2280 Logic Signal Connections: 324 ftBGA (Cont.)

LCMxo2280				
Ball Number	Ball Function	Bank	Dual Function	Differential
E13	PT16D	1		C
C15	PT16C	1		T
F13	PT16B	1		C
D14	PT16A	1		T
A18	PT15D	1		C
B17	PT15C	1		T
A16	PT15B	1		C
A17	PT15A	1		T
VCC	VCC	-		
D13	PT14D	1		C
F12	PT14C	1		T
C14	PT14B	1		C
E12	PT14A	1		T
C13	PT13D	1		C
B16	PT13C	1		T
B15	PT13B	1		C
A15	PT13A	1		T
VCCIO1	VCCIO1	1		
GND	GNDIO1	1		
B14	PT12F	1		C
A14	PT12E	1		T
D12	PT12D	1		C
F11	PT12C	1		T
B13	PT12B	1		C
A13	PT12A	1		T
C12	PT11D	1		C
GND	GND	-		
B12	PT11C	1		T
E11	PT11B	1		C
D11	PT11A	1		T
C11	PT10F	1		C
A12	PT10E	1		T
VCCIO1	VCCIO1	1		
GND	GNDIO1	1		
F10	PT10D	1		C
D10	PT10C	1		T
B11	PT10B	1	PCLK1_1***	C
A11	PT10A	1		T
E10	PT9D	1		C
C10	PT9C	1		T
D9	PT9B	1	PCLK1_0***	C
E9	PT9A	1		T
B10	PT8F	0		C

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo256E-3TN100I	256	1.2V	78	-3	Lead-Free TQFP	100	IND
LCMxo256E-4TN100I	256	1.2V	78	-4	Lead-Free TQFP	100	IND
LCMxo256E-3MN100I	256	1.2V	78	-3	Lead-Free csBGA	100	IND
LCMxo256E-4MN100I	256	1.2V	78	-4	Lead-Free csBGA	100	IND

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo640E-3TN100I	640	1.2V	74	-3	Lead-Free TQFP	100	IND
LCMxo640E-4TN100I	640	1.2V	74	-4	Lead-Free TQFP	100	IND
LCMxo640E-3MN100I	640	1.2V	74	-3	Lead-Free csBGA	100	IND
LCMxo640E-4MN100I	640	1.2V	74	-4	Lead-Free csBGA	100	IND
LCMxo640E-3TN144I	640	1.2V	113	-3	Lead-Free TQFP	144	IND
LCMxo640E-4TN144I	640	1.2V	113	-4	Lead-Free TQFP	144	IND
LCMxo640E-3MN132I	640	1.2V	101	-3	Lead-Free csBGA	132	IND
LCMxo640E-4MN132I	640	1.2V	101	-4	Lead-Free csBGA	132	IND
LCMxo640E-3BN256I	640	1.2V	159	-3	Lead-Free caBGA	256	IND
LCMxo640E-4BN256I	640	1.2V	159	-4	Lead-Free caBGA	256	IND
LCMxo640E-3FTN256I	640	1.2V	159	-3	Lead-Free ftBGA	256	IND
LCMxo640E-4FTN256I	640	1.2V	159	-4	Lead-Free ftBGA	256	IND

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo1200E-3TN100I	1200	1.2V	73	-3	Lead-Free TQFP	100	IND
LCMxo1200E-4TN100I	1200	1.2V	73	-4	Lead-Free TQFP	100	IND
LCMxo1200E-3TN144I	1200	1.2V	113	-3	Lead-Free TQFP	144	IND
LCMxo1200E-4TN144I	1200	1.2V	113	-4	Lead-Free TQFP	144	IND
LCMxo1200E-3MN132I	1200	1.2V	101	-3	Lead-Free csBGA	132	IND
LCMxo1200E-4MN132I	1200	1.2V	101	-4	Lead-Free csBGA	132	IND
LCMxo1200E-3BN256I	1200	1.2V	211	-3	Lead-Free caBGA	256	IND
LCMxo1200E-4BN256I	1200	1.2V	211	-4	Lead-Free caBGA	256	IND
LCMxo1200E-3FTN256I	1200	1.2V	211	-3	Lead-Free ftBGA	256	IND
LCMxo1200E-4FTN256I	1200	1.2V	211	-4	Lead-Free ftBGA	256	IND

Part Number	LUTs	Supply Voltage	I/Os	Grade	Package	Pins	Temp.
LCMxo2280E-3TN100I	2280	1.2V	73	-3	Lead-Free TQFP	100	IND
LCMxo2280E-4TN100I	2280	1.2V	73	-4	Lead-Free TQFP	100	IND
LCMxo2280E-3TN144I	2280	1.2V	113	-3	Lead-Free TQFP	144	IND
LCMxo2280E-4TN144I	2280	1.2V	113	-4	Lead-Free TQFP	144	IND
LCMxo2280E-3MN132I	2280	1.2V	101	-3	Lead-Free csBGA	132	IND
LCMxo2280E-4MN132I	2280	1.2V	101	-4	Lead-Free csBGA	132	IND
LCMxo2280E-3BN256I	2280	1.2V	211	-3	Lead-Free caBGA	256	IND
LCMxo2280E-4BN256I	2280	1.2V	211	-4	Lead-Free caBGA	256	IND
LCMxo2280E-3FTN256I	2280	1.2V	211	-3	Lead-Free ftBGA	256	IND
LCMxo2280E-4FTN256I	2280	1.2V	211	-4	Lead-Free ftBGA	256	IND
LCMxo2280E-3FTN324I	2280	1.2V	271	-3	Lead-Free ftBGA	324	IND
LCMxo2280E-4FTN324I	2280	1.2V	271	-4	Lead-Free ftBGA	324	IND



MachXO Family Data Sheet

Revision History

June 2013

Data Sheet DS1002

Revision History

Date	Version	Section	Change Summary
February 2005	01.0	—	Initial release.
October 2005	01.1	Introduction	Distributed RAM information in family table updated. Added footnote 1 - fpBGA packaging to the family selection guide.
		Architecture	sysIO Buffer section updated.
			Hot Socketing section updated.
			Sleep Mode section updated.
			SLEEP Pin Characteristics section updated.
			Oscillator section updated.
		DC and Switching Characteristics	Security section updated.
			Recommended Operating Conditions table updated.
			DC Electrical Characteristics table updated.
			Supply Current (Sleep Mode) table added with LCMXO256/640 data.
			Supply Current (Standby) table updated with LCMXO256/640 data.
			Initialization Supply Current table updated with LCMXO256/640 data.
			Programming and Erase Flash Supply Current table updated with LCMXO256/640 data.
			Register-to-Register Performance table updated (rev. A 0.16).
			External Switching Characteristics table updated (rev. A 0.16).
			Internal Timing Parameter table updated (rev. A 0.16).
			Family Timing Adders updated (rev. A 0.16).
			sysCLOCK Timingupdated (rev. A 0.16).
			MachXO "C" Sleep Mode Timing updated (A 0.16).
		Pinout Information	JTAG Port Timing Specification updated (rev. A 0.16).
			SLEEPIN description updated.
			Pin Information Summary updated.
			Power Supply and NC Connection table has been updated.
		Ordering Information	Logic Signal Connection section has been updated to include all devices/packages.
			Part Number Description section has been updated.
			Ordering Part Number section has been updated (added LCMXO256C/ LCMXO640C "4W").
		Supplemental Information	MachXO Density Migration Technical Note (TN1097) added.
November 2005	01.2	Pinout Information	Added "Power Supply and NC Connections" summary information for LCMXO1200 and LCMXO2280 in 100 TQFP package.
December 2005	01.3	DC and Switching Characteristics	Supply Current (Standby) table updated with LCMXO1200/2280 data.
		Ordering Information	Ordering Part Number section updated (added LCMXO2280C "4W").
April 2006	02.0	Introduction	Introduction paragraphs updated.
		Architecture	Architecture Overview paragraphs updated.

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Date	Version	Section	Change Summary
November 2006	02.3	DC and Switching Characteristics	Corrections to MachXO "C" Sleep Mode Timing table - value for $t_{WSLEEPN}$ (400ns) changed from max. to min. Value for t_{WAWAKE} (100ns) changed from min. to max.
			Added Flash Download Time table.
December 2006	02.4	Architecture	EBR Asynchronous Reset section added.
		Pinout Information	Power Supply and NC table: Pin/Ball orientation footnotes added.
February 2007	02.5	Architecture	Updated EBR Asynchronous Reset section.
August 2007	02.6	DC and Switching Characteristics	Updated sysIO Single-Ended DC Electrical Characteristics table.
November 2007	02.7	DC and Switching Characteristics	Added JTAG Port Timing Waveforms diagram.
		Pinout Information	Added Thermal Management text section.
		Supplemental Information	Updated title list.
June 2009	02.8	Introduction	Added 0.8-mm 256-pin caBGA package to MachXO Family Selection Guide table.
		Pinout Information	Added Logic Signal Connections table for 0.8-mm 256-pin caBGA package.
		Ordering Information	Updated Part Number Description diagram and Ordering Part Number tables with 0.8-mm 256-pin caBGA package information.
July 2010	02.9	DC and Switching Characteristics	Updated sysCLOCK PLL Timing table.
June 2013	03.0	All	Updated document with new corporate logo.
		Architecture	Architecture Overview – Added information on the state of the register on power up and after configuration.
		DC and Switching Characteristics	MachXO1200 and MachXO2280 Hot Socketing Specifications table – Removed footnote 4.
			Added MachXO Programming/Erase Specifications table.